



## Dual P-Channel 20-V (D-S) MOSFET

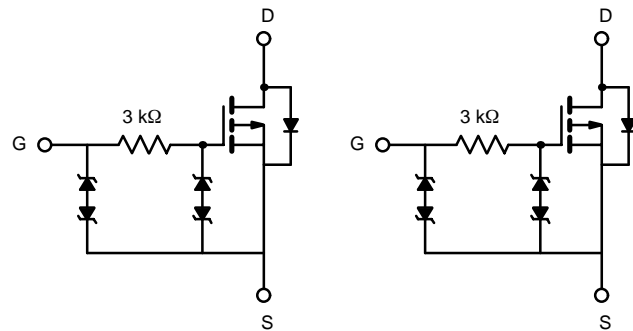
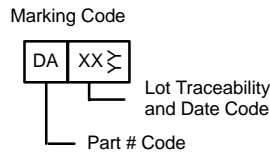
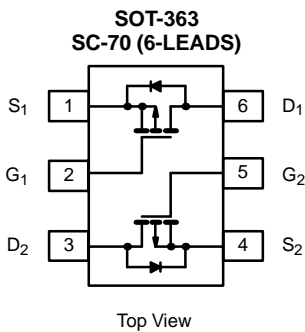
PRODUCT SUMMARY		
$V_{DS}$ (V)	$r_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)
-20	0.490 @ $V_{GS} = -4.5$ V	-1.0
	0.750 @ $V_{GS} = -2.5$ V	-0.81
	1.10 @ $V_{GS} = -1.8$ V	-0.67

### FEATURES

- TrenchFET® Power MOSFETS: 1.8-V Rated
- ESD Protected: 3000 V
- Thermally Enhanced SC-70 Package

### APPLICATIONS

- Load Switching
- PA Switch
- Level Switch



### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

Parameter	Symbol	5 secs	Steady State	Unit	
Drain-Source Voltage	$V_{DS}$	-20		V	
Gate-Source Voltage	$V_{GS}$	$\pm 12$			
Continuous Drain Current ( $T_J = 150^\circ\text{C}$ ) <sup>a</sup>	$I_D$	$T_A = 25^\circ\text{C}$	-1.0	-0.88	A
		$T_A = 85^\circ\text{C}$	-0.72	-0.63	
Pulsed Drain Current	$I_{DM}$	-3			
Continuous Diode Current (Diode Conduction) <sup>a</sup>	$I_S$	-0.61	-0.48		
Maximum Power Dissipation <sup>a</sup>	$P_D$	$T_A = 25^\circ\text{C}$	0.74	0.57	W
		$T_A = 85^\circ\text{C}$	0.38	0.30	
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to 150		$^\circ\text{C}$	

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>a</sup>	$R_{thJA}$	$t \leq 5$ sec	130	170	$^\circ\text{C/W}$
		Steady State	170	220	
Maximum Junction-to-Foot (Drain)	$R_{thJF}$	80	100		

Notes

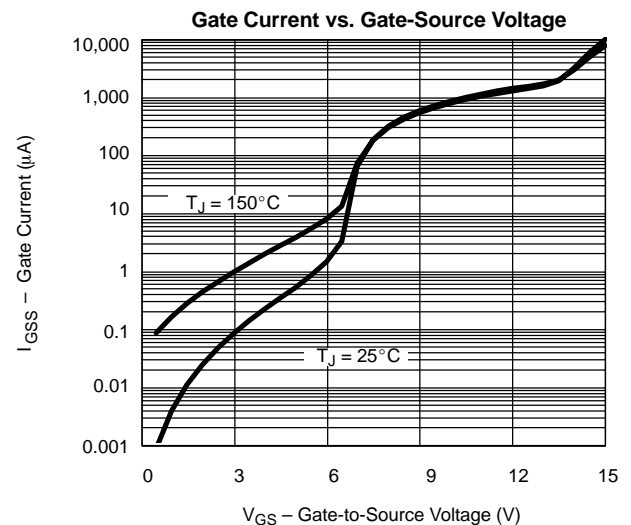
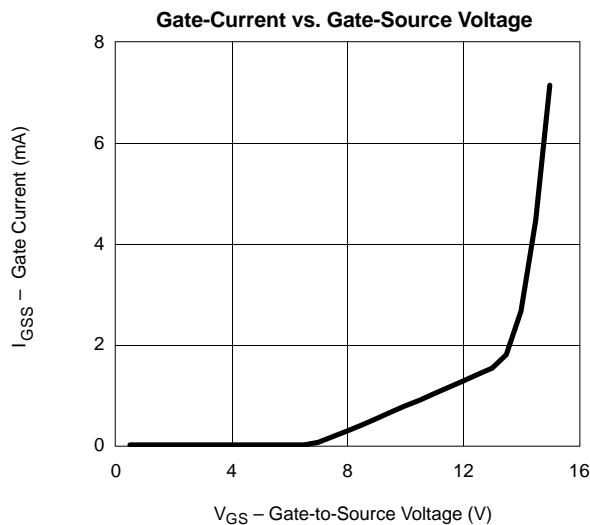
a. Surface Mounted on 1" x 1" FR4 Board.

**SPECIFICATIONS ( $T_J = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Static</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -100\ \mu\text{A}$	-0.45			V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\ \text{V}, V_{GS} = \pm 4.5\ \text{V}$			$\pm 1.5$	$\mu\text{A}$
		$V_{DS} = 0\ \text{V}, V_{GS} = \pm 12\ \text{V}$			$\pm 10$	mA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -16\ \text{V}, V_{GS} = 0\ \text{V}$			-1	$\mu\text{A}$
		$V_{DS} = -16\ \text{V}, V_{GS} = 0\ \text{V}, T_J = 85^\circ\text{C}$			-5	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} = -5\ \text{V}, V_{GS} = -4.5\ \text{V}$	-2			A
Drain-Source On-State Resistance <sup>a</sup>	$r_{DS(on)}$	$V_{GS} = -4.5\ \text{V}, I_D = -0.88\ \text{A}$		0.400	0.490	$\Omega$
		$V_{GS} = -2.5\ \text{V}, I_D = -0.71\ \text{A}$		0.610	0.750	
		$V_{GS} = -1.8\ \text{V}, I_D = -0.2\ \text{A}$		0.850	1.10	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = -10\ \text{V}, I_D = -0.88\ \text{A}$		1.5		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = -0.47\ \text{A}, V_{GS} = 0\ \text{V}$		-0.85	-1.2	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = -10\ \text{V}, V_{GS} = -4.5\ \text{V}, I_D = -0.88\ \text{A}$		1.2	1.8	nC
Gate-Source Charge	$Q_{gs}$			0.3		
Gate-Drain Charge	$Q_{gd}$			0.3		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -10\ \text{V}, R_L = 20\ \Omega$ $I_D \cong -0.5\ \text{A}, V_{GEN} = -4.5\ \text{V}, R_G = 6\ \Omega$		0.150	0.23	$\mu\text{s}$
Rise Time	$t_r$			0.480	0.72	
Turn-Off Delay Time	$t_{d(off)}$			0.840	1.2	
Fall Time	$t_f$			0.850	1.2	

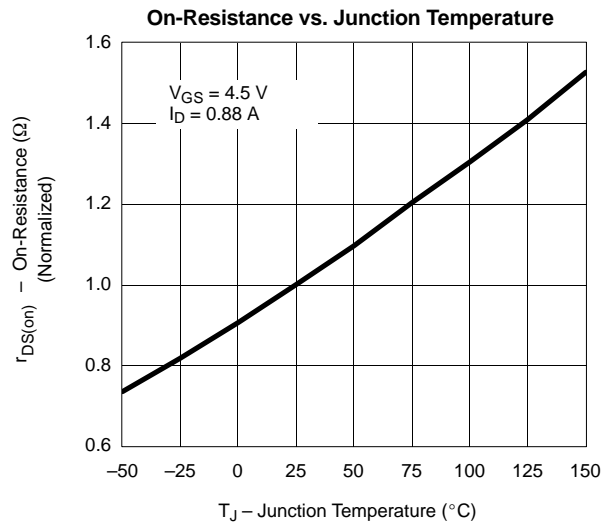
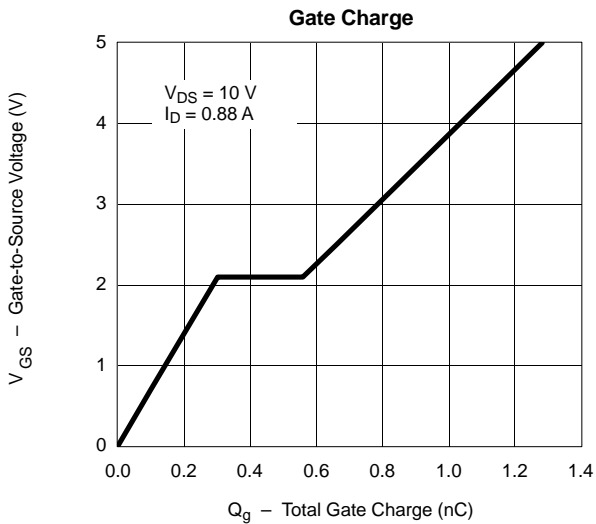
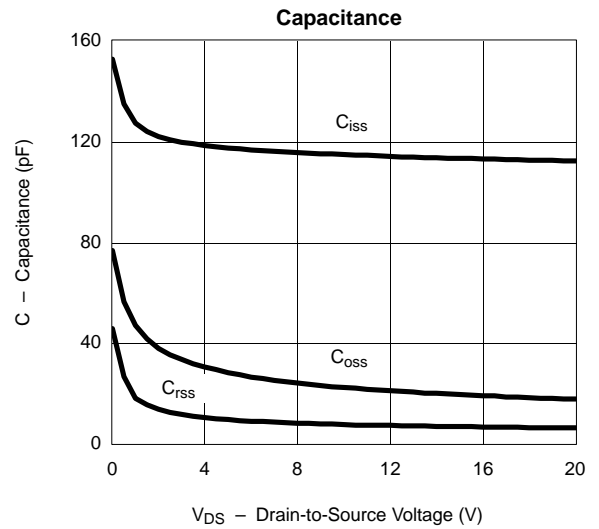
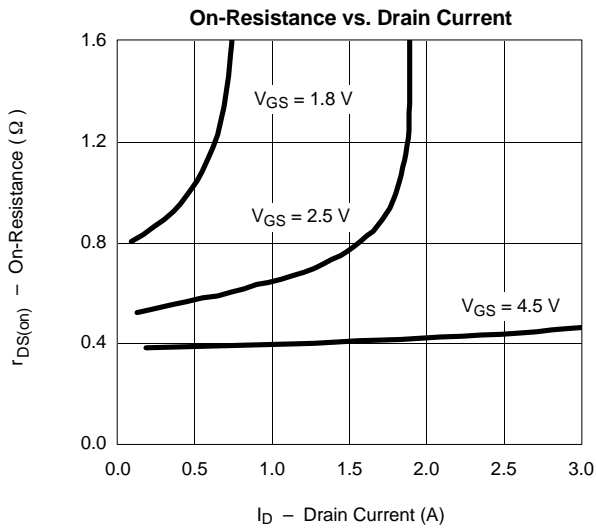
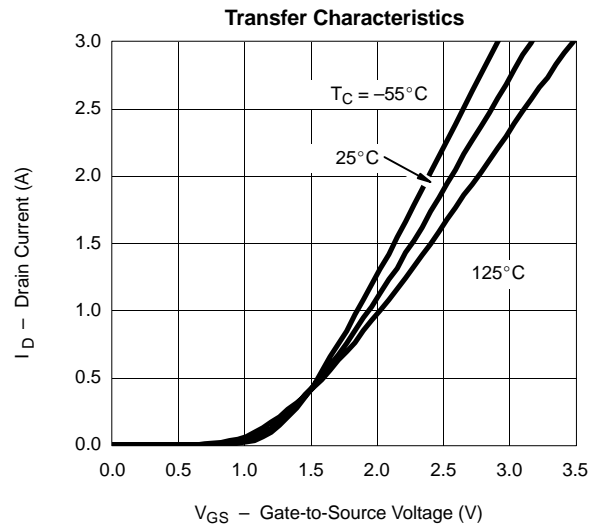
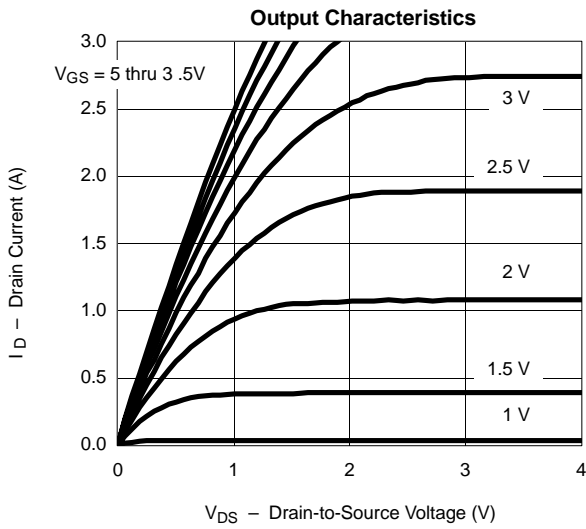
## Notes

- a. Pulse test; pulse width  $\leq 300\ \mu\text{s}$ , duty cycle  $\leq 2\%$ .  
b. Guaranteed by design, not subject to production testing.

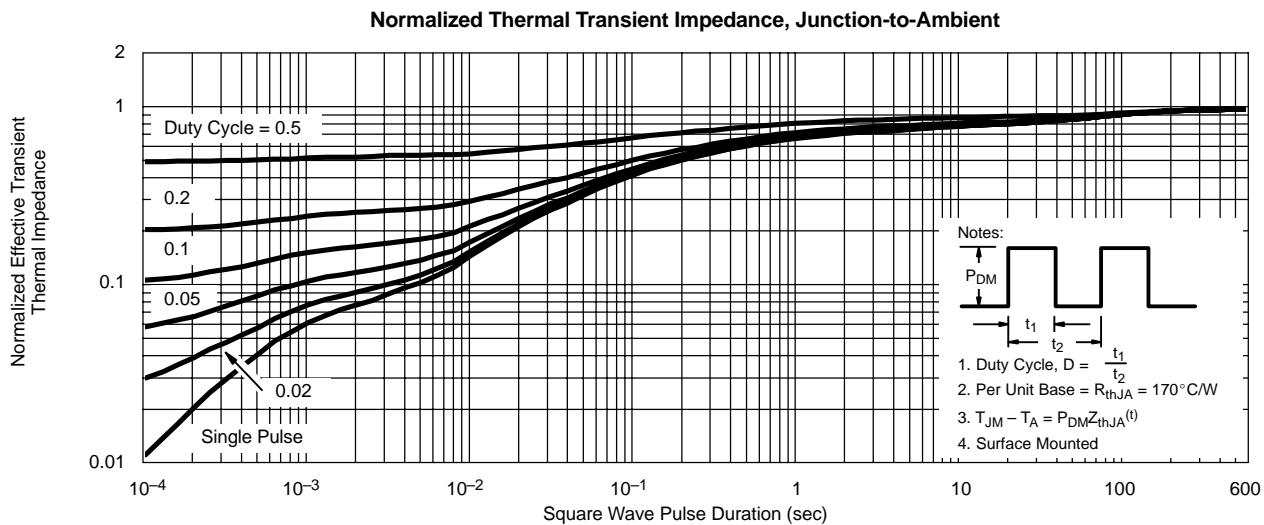
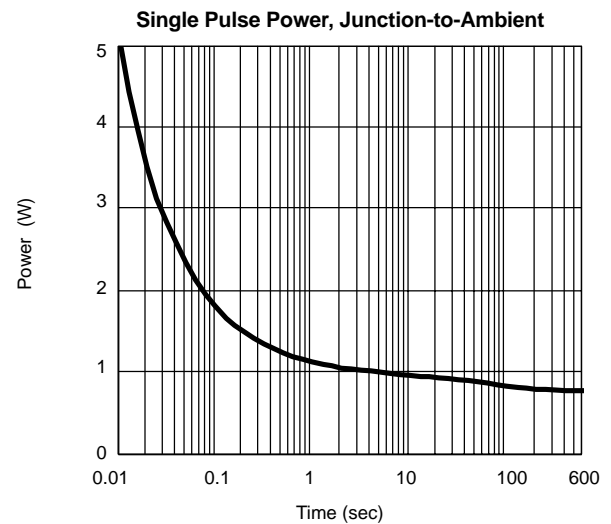
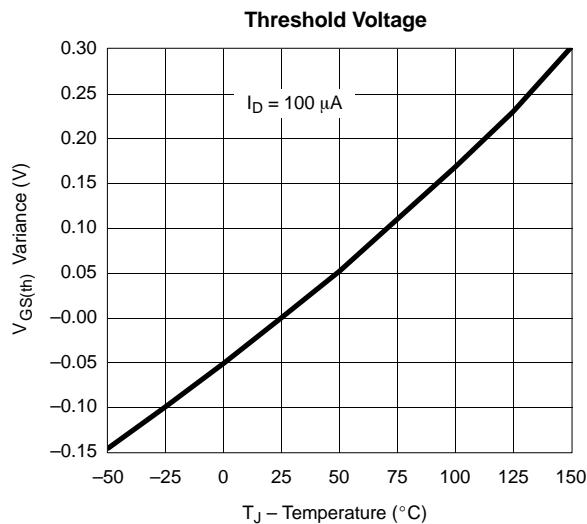
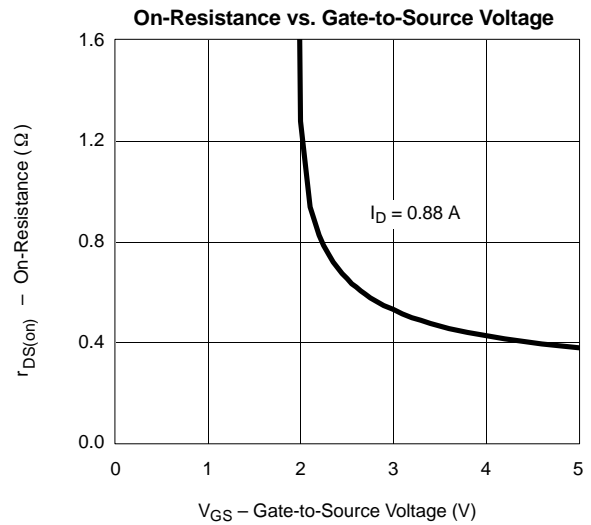
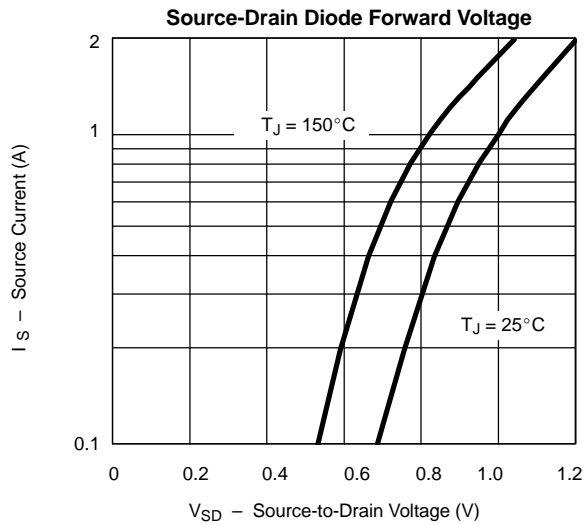
**TYPICAL CHARACTERISTICS ( $25^\circ\text{C}$  UNLESS NOTED)**



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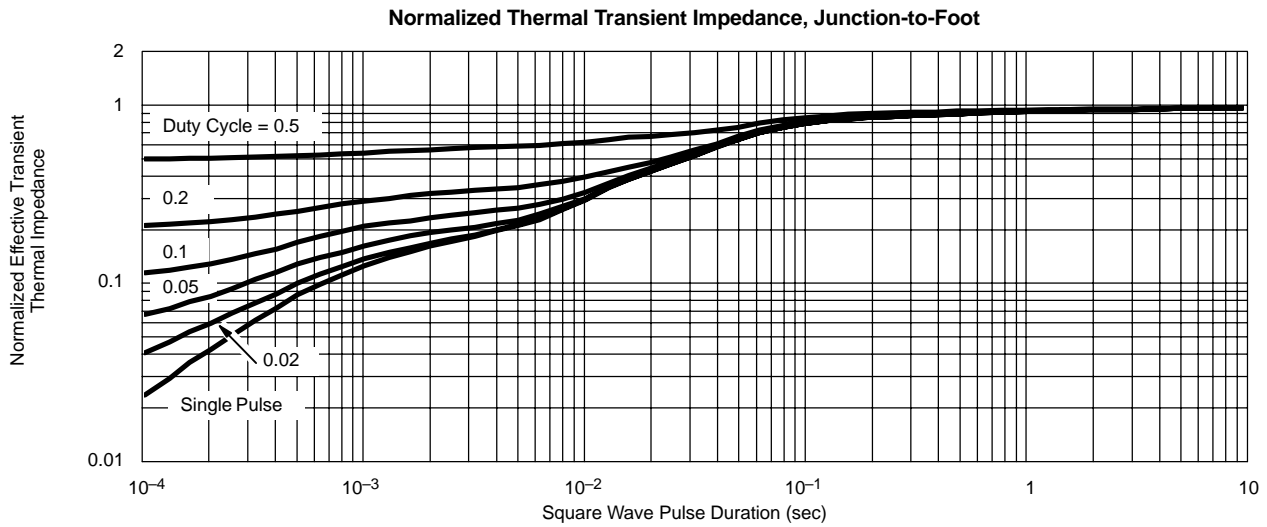


**TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)**





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